



PRELIMINARY

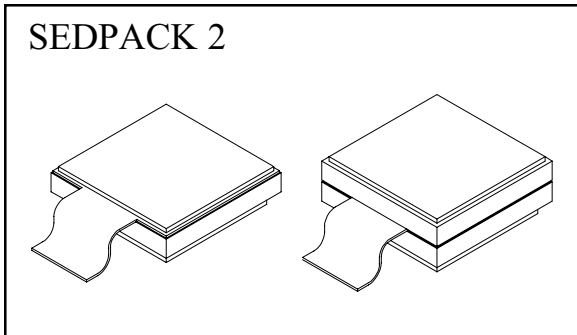
# SOLID STATE DEVICES, INC.

14830 Valley View Blvd \* La Mirada, Ca 90638  
Phone: (562) 404-7855 \* Fax: (562) 404-1773

## Designer's Data Sheet

**SED30KE600**  
**SED30KW600**

**30 AMP**  
**600 VOLTS**  
**HYPER FAST**  
**RECTIFIER**



- FEATURES:**
- Low Forward Voltage Drop
  - Low Reverse Leakage
  - Surface Mountable Package
  - Guard Ring for Overvoltage Protection and Ruggedness
  - 150°C Operating Temperature
  - Hermetically Sealed Package
  - Eutectic Die Attach
  - Hyper Fast Soft Recovery
  - TX, TXV and Space Level Screening Available

Maximum Ratings	SYMBOL	VALUE	UNITS
Peak Repetitive Reverse and DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	600	Volts
Average Rectified Forward Current (Resistive Load, 60Hz, Sine Wave, $T_C = 100^\circ\text{C}$ )	$I_o$	30	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave Superimposed on $I_o$ , allow junction to reach equilibrium between pulses, $T_C = 100^\circ\text{C}$ )	$I_{FSM}$	300	Amps
Operating and Storage Temperature	Top & Tstg	-55 TO +150	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	0.9	°C/W

**NOTE:** All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

**DATA SHEET #: RC0044A**

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Electrical Characteristics		SYMBOL	VALUE	UNITS
<b>Instantaneous Forward Voltage Drop</b> ( $T_A = 25^\circ\text{C}$ , 300 $\mu\text{s}$ Pulse)	$I_F = 20\text{A}_{\text{DC}}$	$V_{F1}$	<b>1.15</b>	$V_{\text{DC}}$
	$I_F = 30\text{A}_{\text{DC}}$	$V_{F2}$	<b>1.30</b>	
<b>Minimum Reverse Blocking Voltage</b> ( $I_R = 100\mu\text{A}$ , 300 $\mu\text{sec}$ pulse minimum)		$BV_R$	<b>600</b>	$V_{\text{DC}}$
<b>Reverse Leakage Current</b> ( $V_R = 480\text{V}$ , 300 $\mu\text{sec}$ pulse minimum)	$T_A = 25^\circ\text{C}$	$I_{R1}$	<b>0.50</b>	$\mu\text{A}$
	$T_A = 125^\circ\text{C}$	$I_{R2}$	<b>5</b>	<b>mA</b>
<b>Junction Capacitance</b> ( $V_R = 5V_{\text{DC}}$ , $T_A = 25^\circ\text{C}$ , $f = 1\text{MHz}$ )		$C_J$	<b>5000</b>	<b>pF</b>
<b>Reverse Recovery Time</b> ( $I_F = 500\text{mA}$ , $I_R = 1\text{A}$ , $I_{\text{RR}} = 250\text{mA}$ , $T_A = 25^\circ\text{C}$ )		$t_{\text{RR}}$	<b>35</b>	<b>nsec</b>

**CASE OUTLINE:**  
**P/N SED30KE600**

**CASE OUTLINE:**  
**P/N SED30KW600**

